

The measurements of irradiation sensors

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Contents

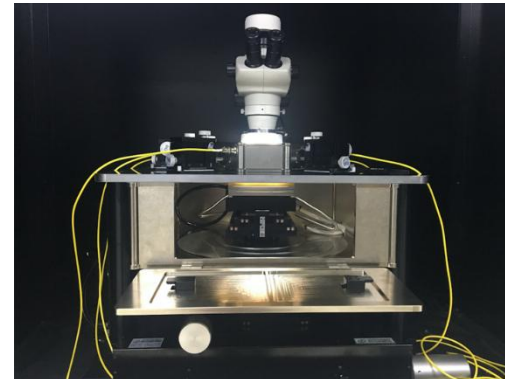
-- Using probe station which has cold chuck



-- This time, we only show preliminary results without cold temperature setting. All measure at room temperature: 20-22°C and GRfloating.

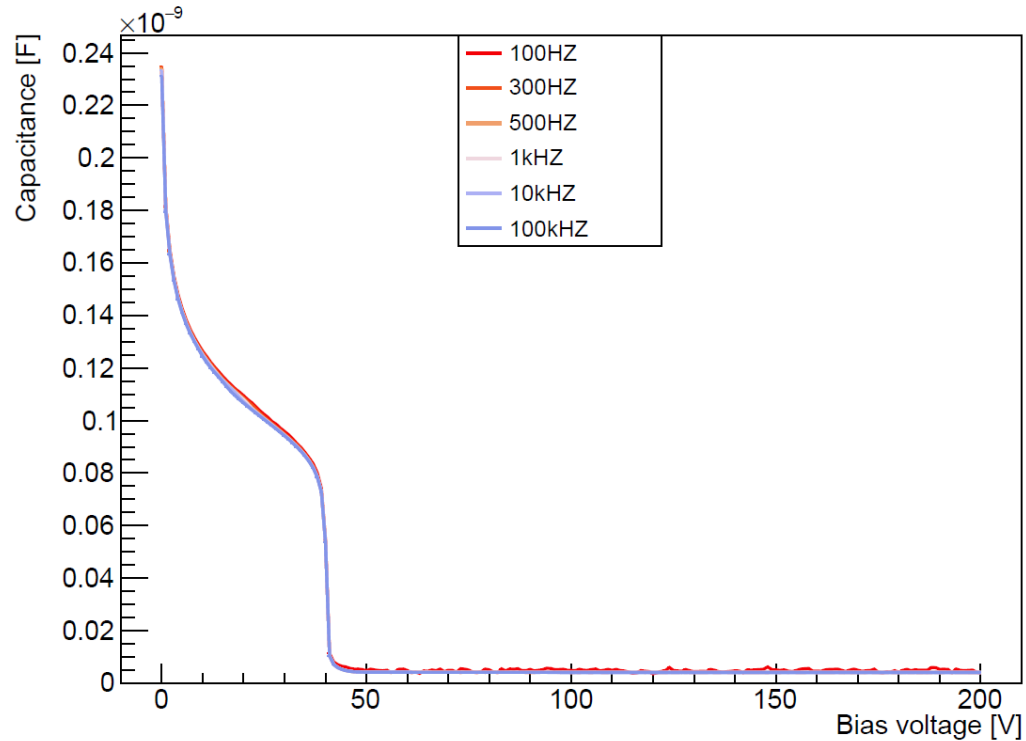
-- C-V scan

- Different frequencies
- Different irradiation

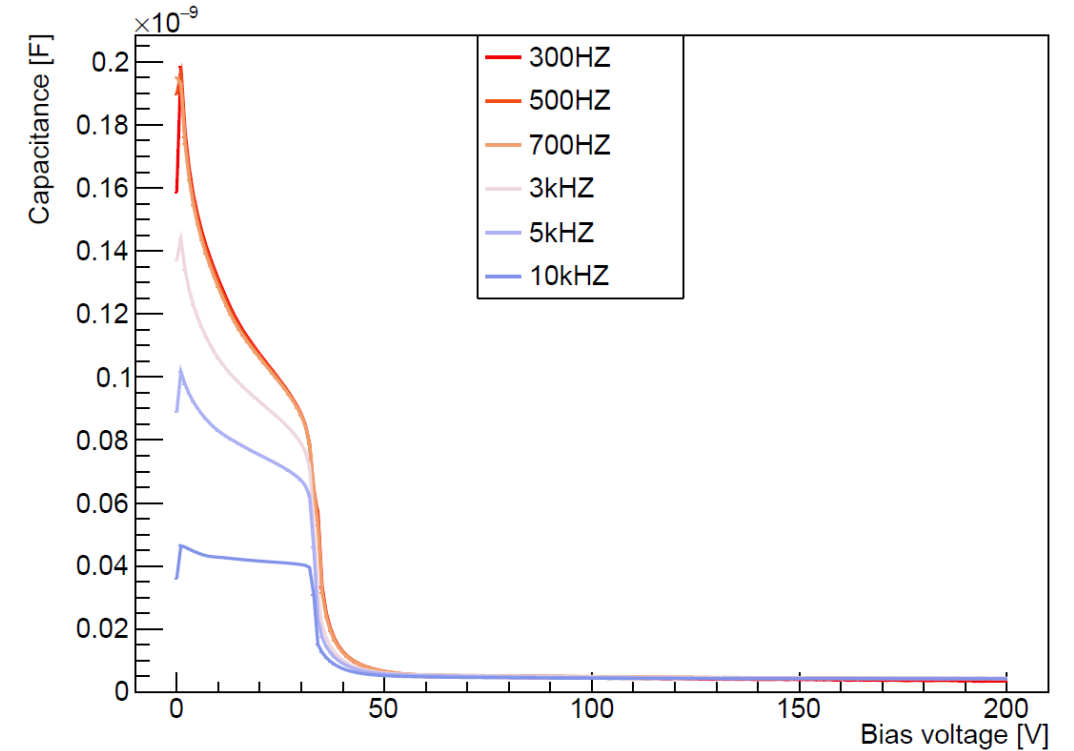


Effect of frequency:

Effect of frequency on W8 capacitance before irradiation :

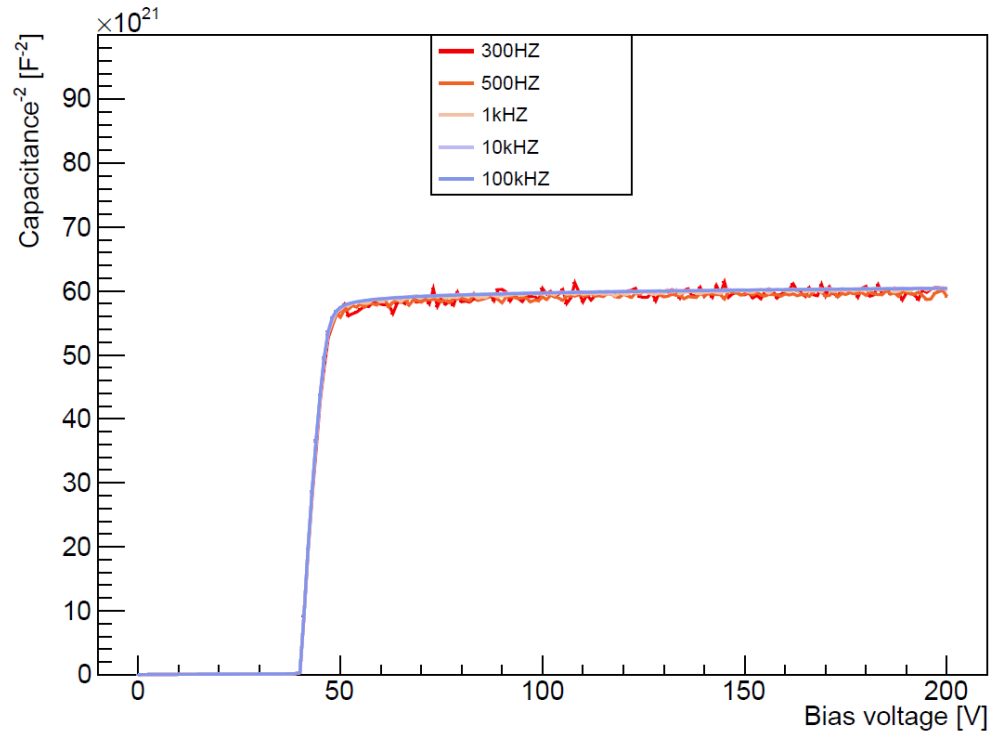


Effect of frequency on W8 capacitance after $4E14$ irradiation:

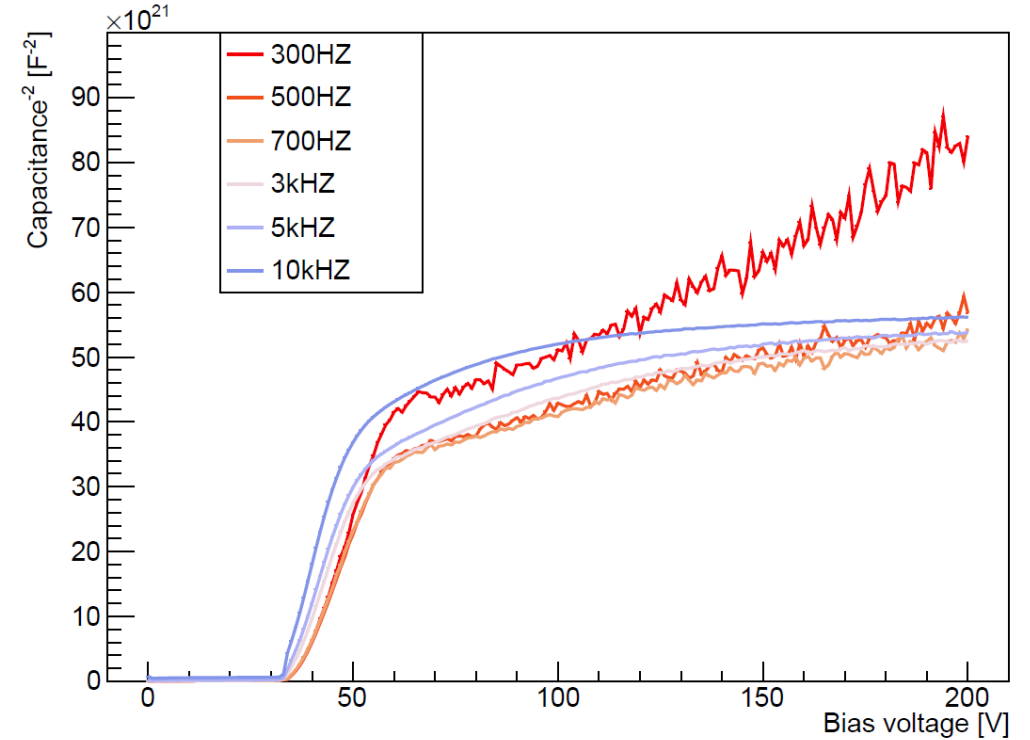


Effect of frequency:

Effect of irradiation on capacitance⁻²
W8 before irradiation:

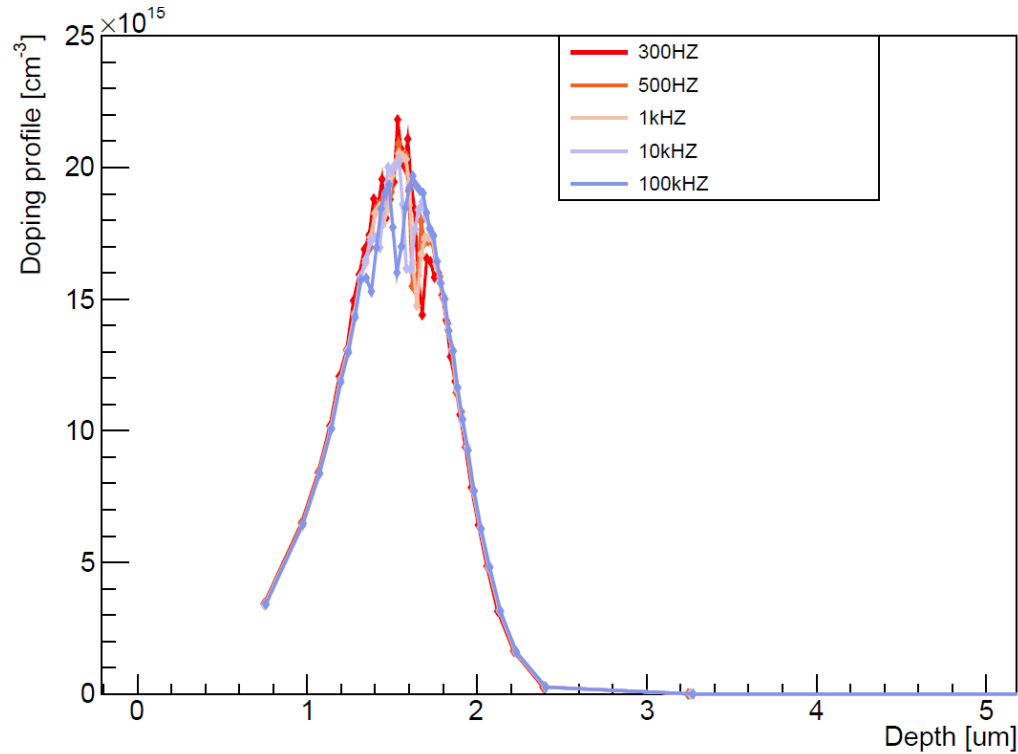


Effect of irradiation on capacitance⁻²
W8 after 4E14 irradiation:

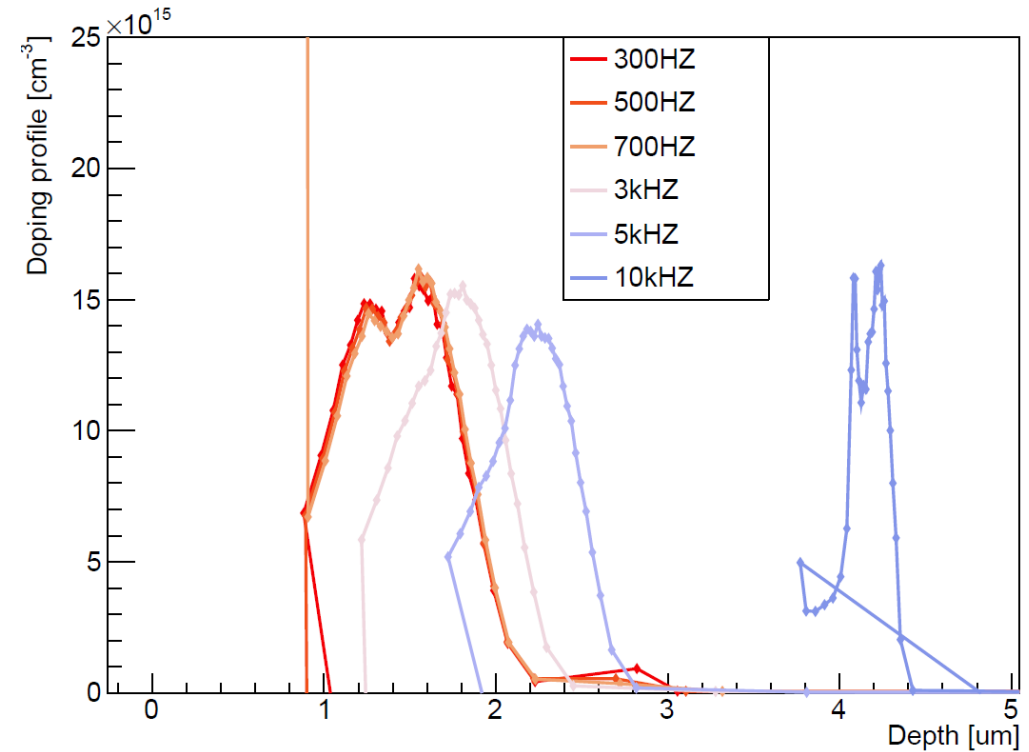


Effect of frequency:

Effect of frequency on W8 doping profile before irradiation:



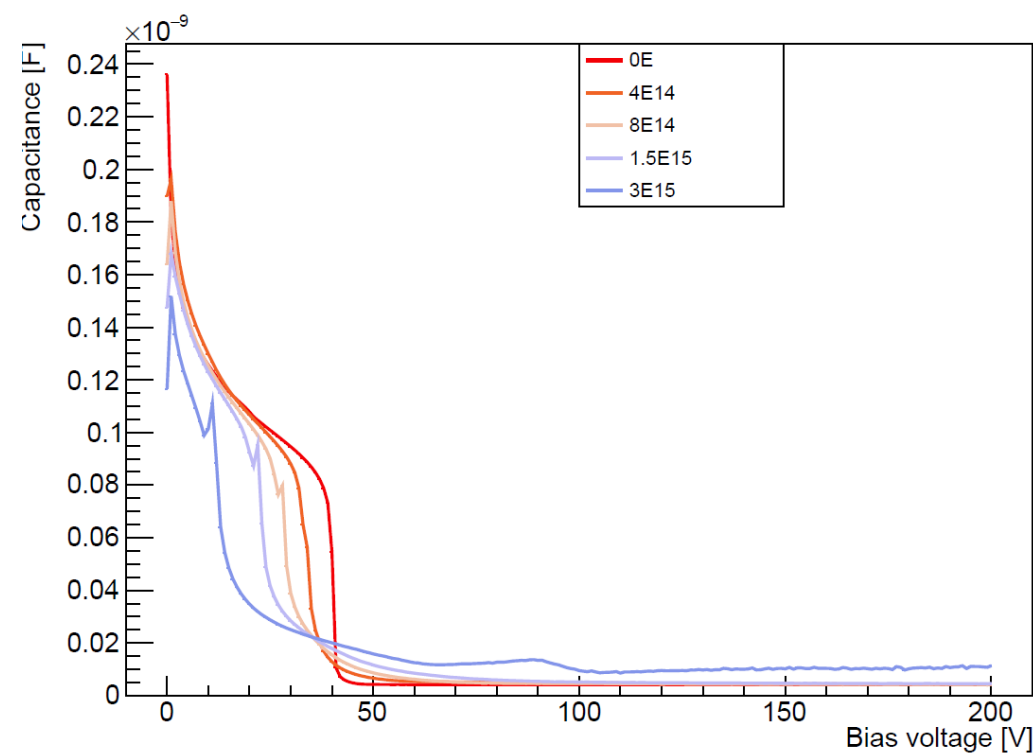
Effect of frequency on W8 doping profile after $4\text{E}14$ irradiation :



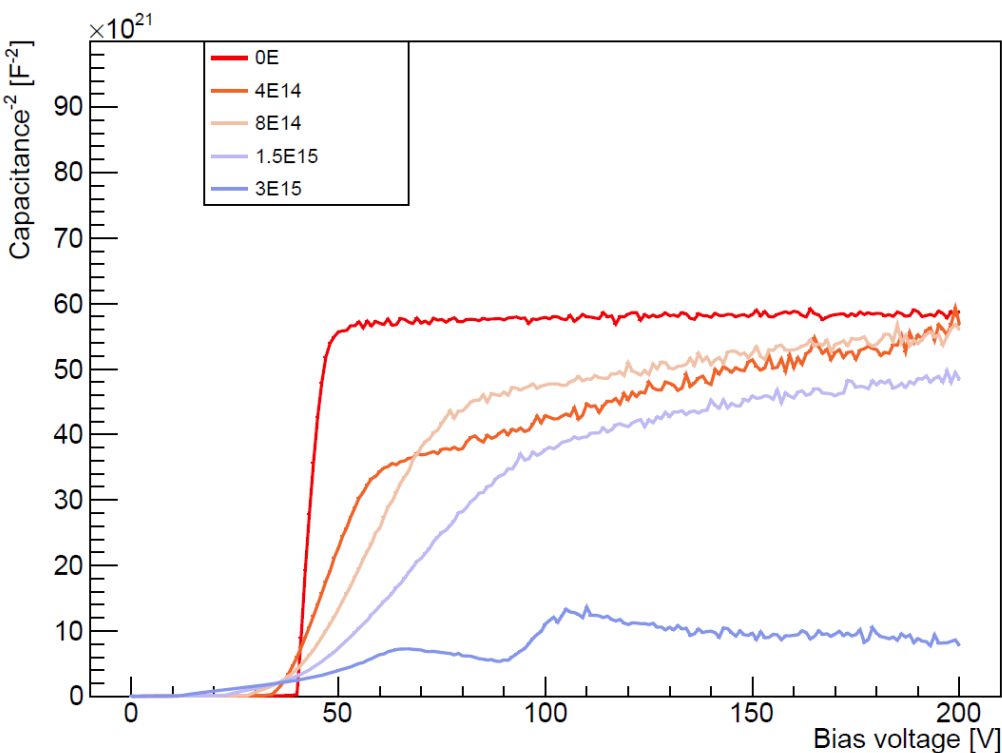
Multiplication layer movement? Around 500 frequencies, depth is almost unchanged. So we made some measurements with 500HZ.

Effect of irradiation:

Effect of irradiation on capacitance
W8 at 500HZ:

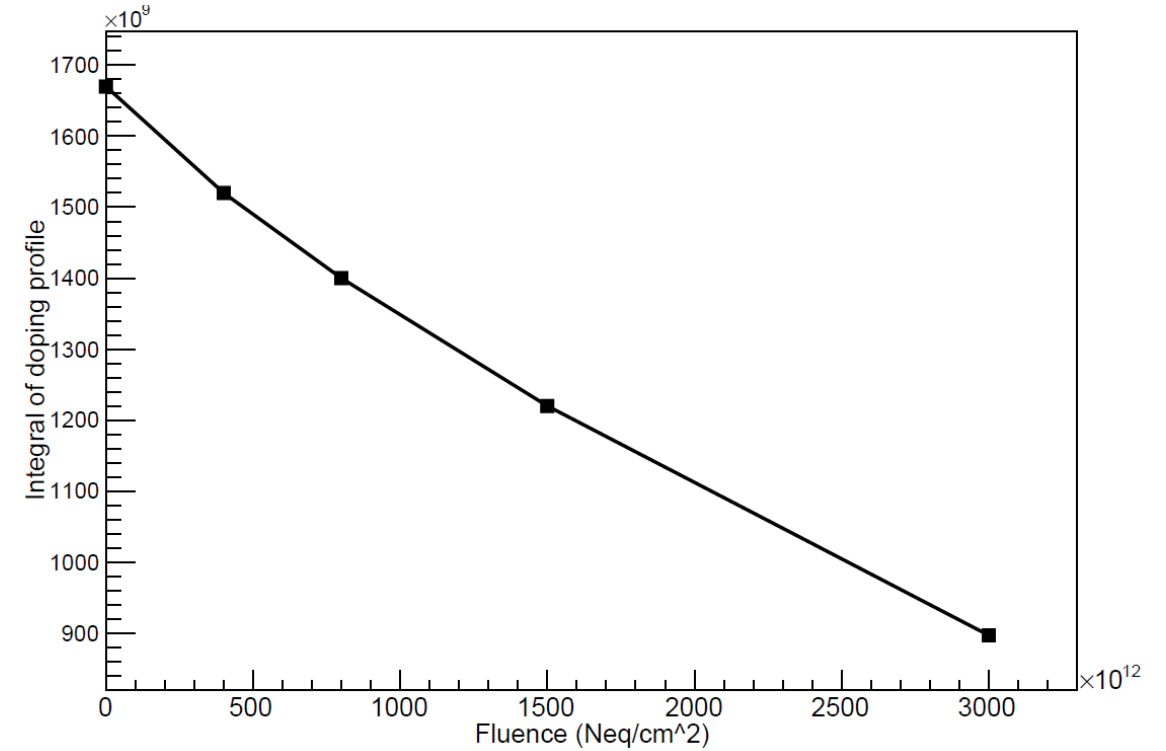
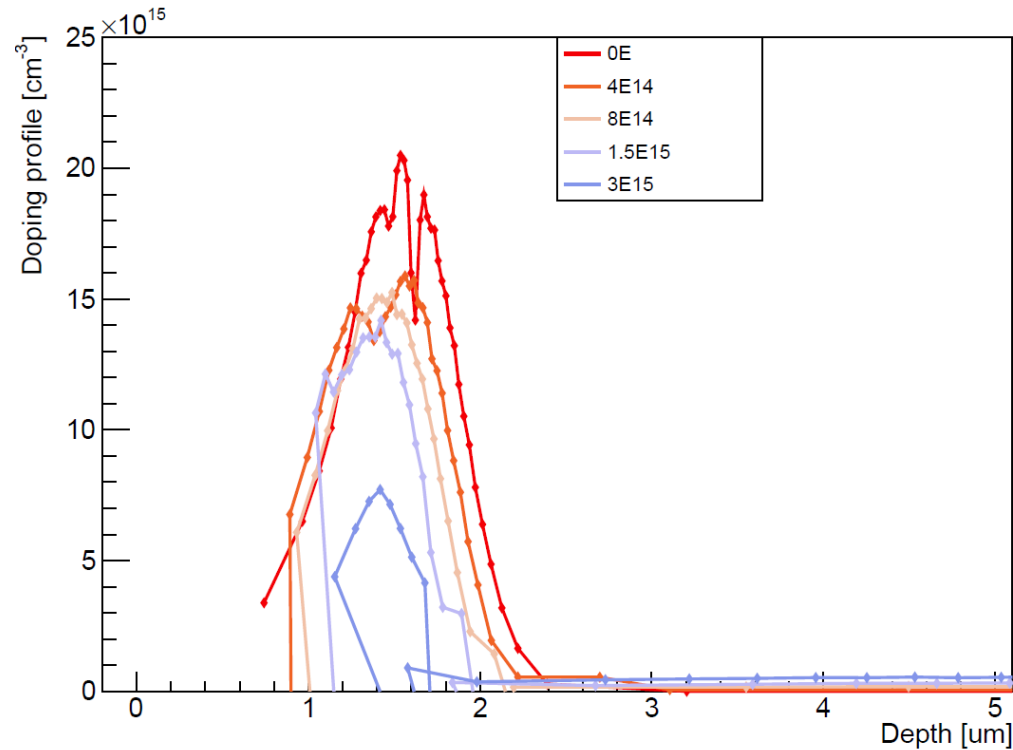


Effect of irradiation on capacitance⁻²
W8 at 500HZ:



Effect of irradiation:

Effect of irradiation on W8 doping profile at 500HZ:



As the irradiation increases, doping profile is decreasing.

Next Plan

- Cold temperature setting
- Measuring I-V and Measuring C-V Again
- GR grounded

100MeV Proton irradiation plan: (China institute of atomic energy)

Irradiation details for LGADs and PiN diodes

one group : 6

Fluence[1 MeV n_{eq}/cm^{-2}]	LGADS	PiN diodes
4×10^{14}	W2,W8,W18	3
8×10^{14}	W2,W8,W18	3
1.5×10^{15}	W2,W8,W18	3
3×10^{15}	W2,W8,W18	3
6×10^{15}	W2,W8,W18	3

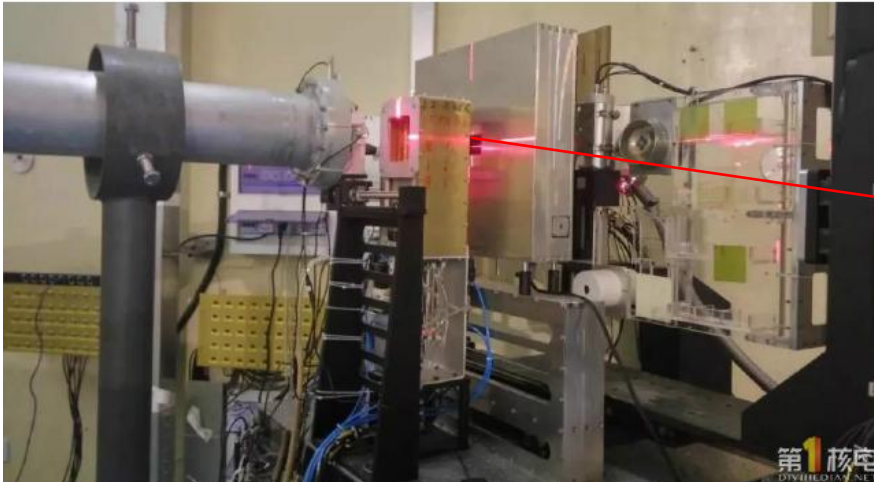
Sensor type: 2 x LG1_SE2, 2 x LG1_SE3, 4 x LG1_SE5, 1 x LG1_SE5_NM, 1 x PIN1_SE5, 1 x PIN1_SE5_NM

SE3: 2.3mm x 2.5mm

SE5: 2.3mm x 2.6mm

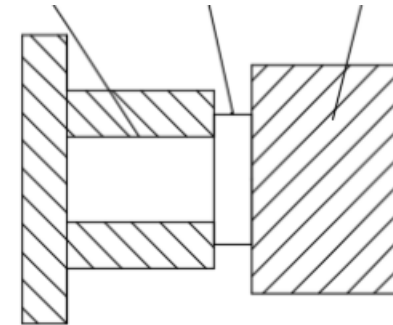
Based on offline measurements.

Station for irradiation in CIAE



Sensor

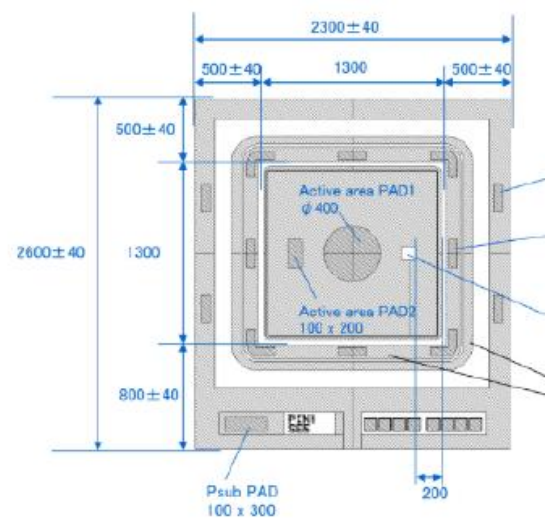
Beam import sensor Beam absorber



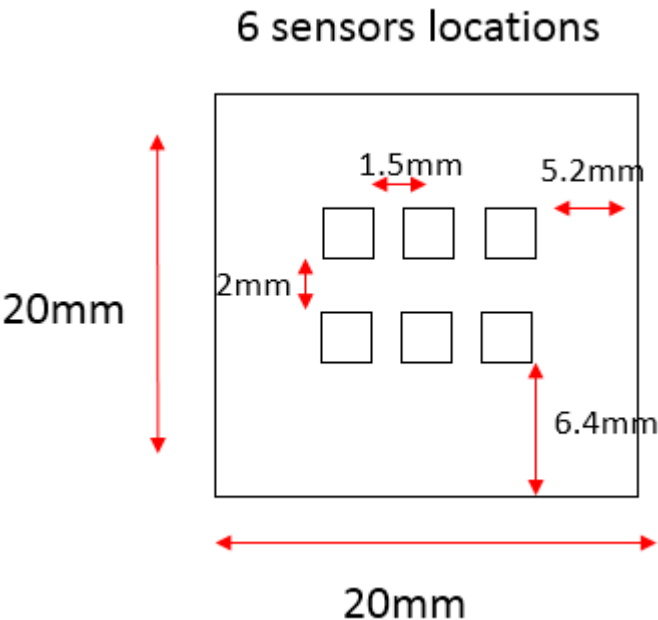
Designed by NanJing University

Sensors placement:

Our Sensor size:
2.3mm×2.6mm or 2.3mm×2.5mm



Based on offline measurements



Multiple sets of simultaneous measurements:
The longer the measurement, the more expensive

Based on offline measurements.

Piezoelectric motor translation stage



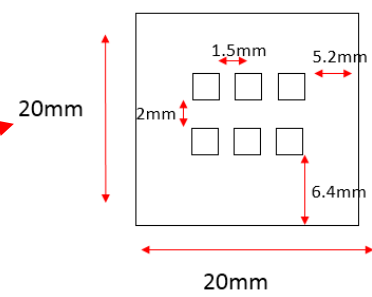
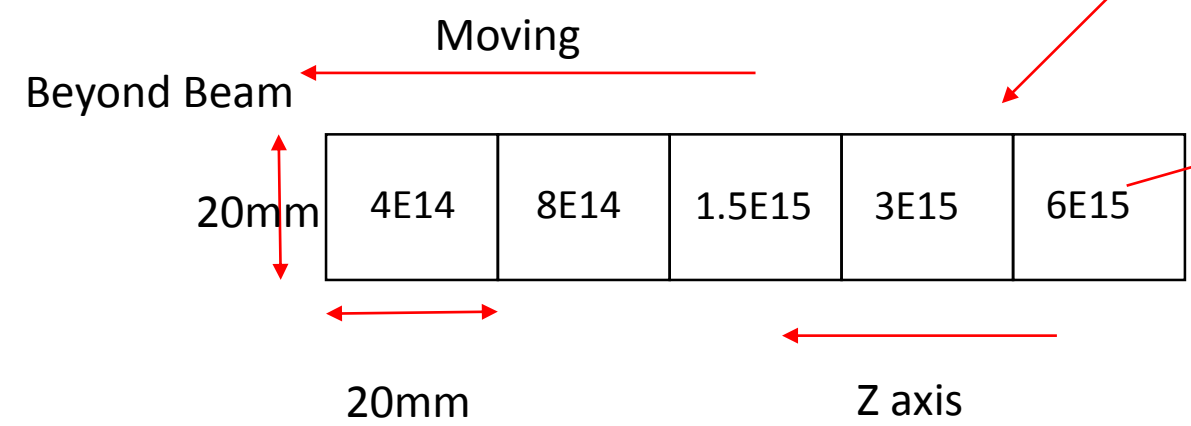
Move back and forth



PC control

Minimum travel range:19mm
Maximum travel range:92mm

Beam size: 20mm×100mm



Time: 4E14: 0.25hours

1.5E15: 1hours

6E15: 4hours

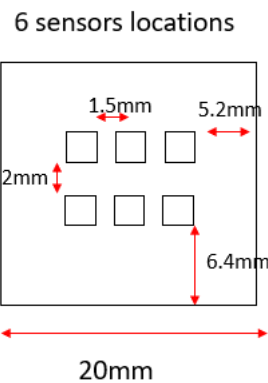
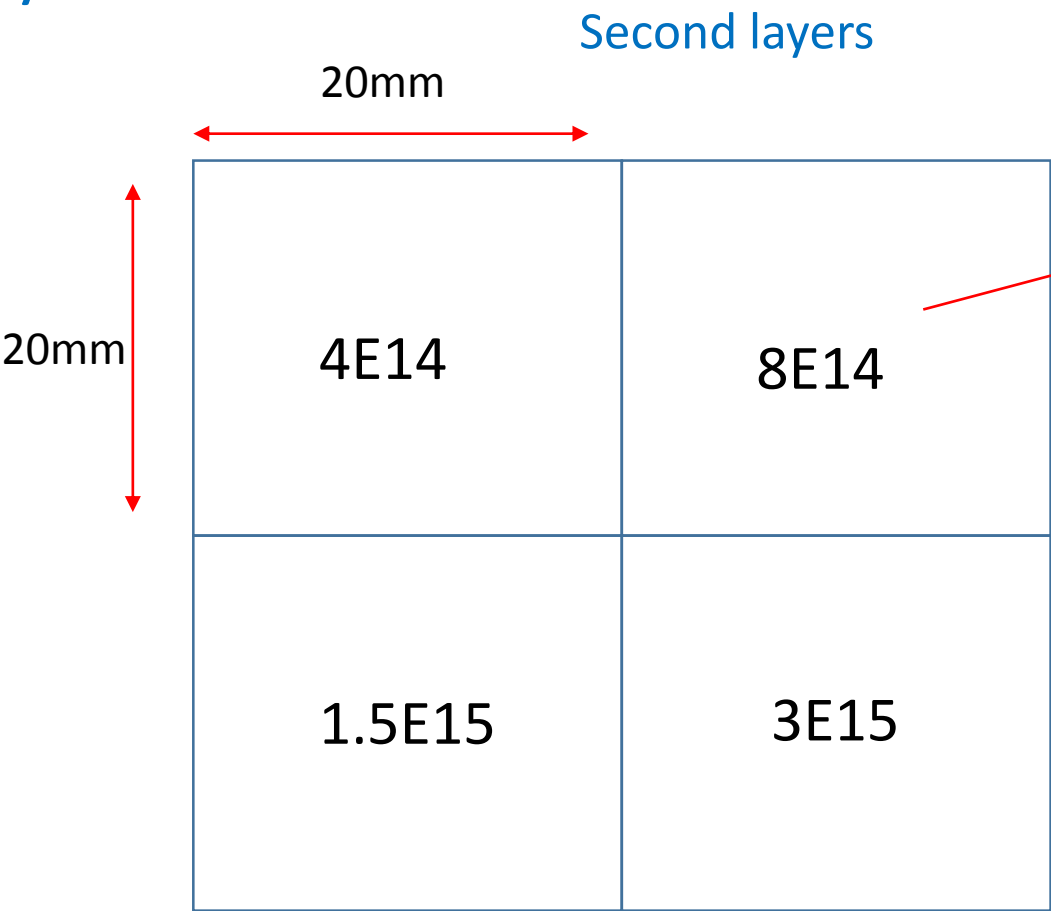
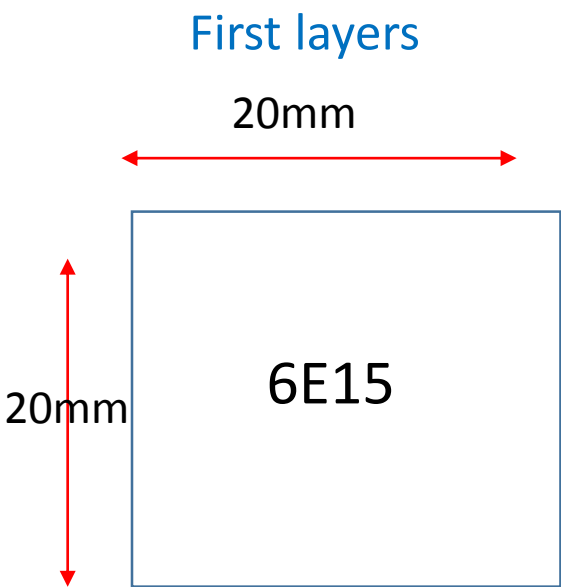
8E14: 0.5hours

3E15: 2hours

Eg.When arrive 0.25hours,
the stage move 20mm.So
the sensors leave the beam
range.

Second option: two layers

Beam size:
20mm×20mm



XY高速电动位移台



PMS
295mm * 260mm * 32.5mm

- 最高速度达200mm/s
- 重复定位精度1μm
- 结构紧凑，适用性广

Question: (already sent to CIAE)

1. How to calculate the irradiation dose or how much time does $6 \times 10^{15} n_{eq}/cm^2$ need?
2. Can the beam size reach 20mm×100mm or 20mm×80mm?
3. Is Beam absorber necessary?
4. What materials can be used to take sensors after one week after irradiation? Lead or Steel?
5. When beam size is 20mm×20mm, is the irradiation dose at the center and the edge the same?

Next Plan:

- Go to China institute of atomic energy next Tuesday